# INVESTIGATION OF FABRICATED TIPS-PENTACENE BASED ORGANIC DIODE USING SLIDE COATING DEPOSITION TECHNIQUE

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### PERPUSTAKAAN Univerbiti Malaysia sabah

# THESIS SUBMITTED IN FULFILLMENT FOR THE DEGREE OF MASTER OF ENGINEERING

FACULTY OF ENGINEERING UNIVERSITI MALAYSIA SABAH 2019



#### **UNIVERSITI MALAYSIA SABAH**

#### BORANG PENGESAHAN STATUS TESIS

INVESTIGATION OF FABRICATED TIPS-PENTACENE BASED JUDUL:

ORGANIC DIODE USING SLIDE COATING DEPOSITION

**TECHNIQUE** 

MASTER OF ENGINEERING (ELECTRICAL AND ELECTRONIC IJAZAH:

**ENGINEERING)** 

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#### **ACKNOWLEDGEMENT**

First and foremost, all praise to Allah s.w.t. for this journey, I know Allah wouldn't test His servant if they are not worthy, when there is a test, there is an answer, Alhamdullilah.

I would also like to express my deepest gratitude and appreciation to my previous supervisor, Dr. Khairul Anuar Mohamad for giving me the chance to pursue this journey. Without him, I may not be able to even start with this journey. Not to forget to my present supervisor, Assc. Prof Dr. Ismail bin Saad who willingly replace Dr Khairul's place as he moved to another university, also giving me all the moral support during my viva voce until the day this thesis was submitted. The road to finish this journey was long and tough but quit was never an option from them. To my internal examiner, Dr. Chee, thank you so much for being so supportive and gave constructive criticism during viva voce and throughout my correction period.

Dearest heartfelt gratitude to my parents who has been supporting me from day one! I can never continue this journey if it wasn't from the positive vibe from both and always calm whenever people around us was asking how my master's progress was. They really believed I could do this, so this is for you Abi and Ome. Love you two so much!

To both of my brothers, Saef and Redha; you two are one of the reasons for me to be strong throughout this journey, hoping that this will sets examples that life is difficult, it is just the matter on how you handle them, get up and fight strong. Thank you for taking care of our cats at home when I was busy in faculty doing experiments, and some house chores that I left out. May Allah showers both of you with "rezeki" on earth and the afterlife.

To my dearest friends who has been helping along the way, big shout out especially Farah Lyana who has been the biggest supporter behind me, who has always lent her ears and time to listen to all the emotional breakdowns



throughout this journey and turns into one of my best friends. Not forgetting A'qilah, who just wants me to mention her name in this column because she's blackmailing me, please send help. Jokes aside, thank you for being one of my inspiration to finish my studies. Seeing how organized and determine you are, makes me only have one road to this journey, which is to finish them.

Last but not least, my experiment partner who is now my husband, Dzul Fahmi. This journey would not be as colorful, fun nor motivating if it wasn't for you. You were always energetic and always knows how to make me see problem in another perspective. Countless days in the lab, argues and discussions, sleepless night and days (until we forgot all the public holidays and weekends) Finally, we did it! We made a good team, thank you for everything.

Fara Naila Binti Rusnan 30 August 2018



#### **ABSTRACT**

Organic material is one of the most capable material to fit into any kinds of substrates as it gained recent popularity for being able to be deposited under low maintenance of manufacturing. The performances are still comparable with non-organic based electronics. The main purpose of this study is to investigate fabricated TIPS-pentacene based organic diode using slide coating deposition technique. Different alignment of deposition method such as dip coating, spin coating and slide coating were compared and used drop casting deposition technique as benchmark. Slide coating has the ability to control the direction of deposition and the drying area as it will influence the quality of device. Optimum condition for depositing TIPS-pentacene were also taken into account where 60 minutes duration used to furnace, and 0.2 weight percentage needed to achieve highly oriented molecular properties. Molecular orientation of slide coated deposition technique has sharp (0 0 1) peak at 5.33° with FWHM of 0.32. This result is comparable with drop casting where 20 angle is 5.27° and FWHM of 0.08. The measured I-V characteristics of the organic diode show rectifying behaviour and non-symmetrical graph, thus the junction is non-ohmic. Extraction of organic diode parameter such as current density, J, turn-on voltage,  $V_7$ , saturation current,  $I_0$ , barrier heights,  $\varphi_b$ , series resistance,  $R_s$ , and ideality factor,  $n_s$ , values at 1.33 x 10<sup>-7</sup> A/cm<sup>2</sup>, 2.22V, 19.32 A, 4.61 x  $10^{\text{-1}}$ , 8.75 x  $10^6\Omega$  and 18, respectively. Comparison research between chloroform and toluene solution to dilute TIPS-pentacene were also discussed in this study based on physical and electrical characterization, where toluene is the most suitable organic solvent to dilute TIPS-pentacene as it benefits more in both aspects compared to chloroform.



#### **ABSTRAK**

### KAJIAN TENTANG ORGANIK DIOD YANG DIFABRIKASI BERASASKAN "TIPS-PENTACENE" MENGGUNAKAN TEKNIK PENYADURAN SECARA MENGGELONGSOR

Bahan organik adalah salah satu daripada bahan yang berkebolehan untuk digunakan dalam pelbagai jenis substrat. Kelebihan tersebut telah menarik perhatian apabila ianya boleh direnap dengan kadar kos penyengaraan pengilangan yang rendah. Prestasi yang diperolehi adalah setanding dengan peranti elektronik bukan organik. Tujuan utama kajian ini adalah untuk mengkaji tentang diod organik yang difabrikasi berasaskan "TIPSpentacene" dengan menggunakan teknik penyalutan secara menggelongsor. Kajian tentang penjajaran bagi setiap teknik salutan; contohnya, penyalutan secara celupan, penyalutan secara putaran dan penyalutan secara menggelongsor, turut dijalankan. Perbandingan setiap penggunaan penjajaran dilakukan, dimana teknik penyalutan secara titisan digunakan sebagai tanda aras kajian. Teknik penyalutan secara menggelongsor mempunyai kelebihan untuk mengawal arah haluan pengenapan dan kawasan pengeringan, di mana faktor-faktor ini akan memberi kesan terhadap kualiti sesebuah peranti. Keadaan optimum bagi proses pengenapan "TIPS-pentacene" turut diambil kira dimana tempoh relauan adalah sepanjang 60 minit dan sejumlah 0.2 peratus berat kering digunakan bagi memperoleh sifat orientasi molekul yang baik. Orientasi molekul bagi Teknik pengenapan secara menggelongsor mempunyak puncak (0 0 1) yang tirus pada 5.33° bersamaan dengan lebar lengkap separa maksimum 0.32. Hasil yang diperoleh adalah setanding dengan teknik pengenapan secara menitis dimana sudut 20 adalah 5.27° dan nilai lebar lengkap separa maksimum sebanyak 0.08. Pengukuran ciri-ciri arus dan voltan bagi diod organic menunjukkan tingkah laku berarus terus dan menghasilkan graf yang tidak simetri, sekaligus memberi gambaran sifat simpang bukan rintangan. Penyarian parameter diod organic seperti ketumpatan arus, J, voltan rangsangan,  $V_7$ , arus termendap,  $I_0$ , ketinggian samar,  $\varphi_b$ , rintangan bersisi,  $R_s$ dan faktor unggul, n, masing-masing memberikan nilai 1.33 x 10-7 A/cm2, 2.22V, 19.32A, 4.61X10-1, 8.75X106 dan 18. Perbandingan bahan pelarut bagi "TIPSpentacene" antara kloroform dan toluene turut dibincangkan dalm kajian ini berdasarkan ciri-ciri fizikal dan elektrik, dimana toleuen adalah bahan pelarut yang paling sesuai kerana ia boleh memberi kelebihan dalam kedua-dua segi berbanding kloroform.



### LIST OF CONTENTS

	PAGE
TITLE	i
DECLARATION	ii
CERTIFICATION	iii
ACKNOWLEDGEMENT	iv
ABSTRACT	vi
ABSTRAK	vii
LIST OF CONTENTS	viii
LIST OF TABLES	xi
LIST OF FIGURES	xii
LIST OF ABBREVIATIONS	xv
LIST OF SYMBOLS	xvi
LIST OF APPENDICES	xvii
CHAPTER 1: INTRODUCTION	
1.1 Background	1
1.2 Problem Statement	1
1.3 Research Objectives	2
1.4 Research Scope	2
1.5 Thesis Outline	3
CHAPTER 2: LITERATURE REVIEW	
2.1 Organic Semiconductors	4
2.2 Polymers	5
2.2.1 Poly(3-alkylthiophene) (P3HT)	5



	2.2.2	Poly(2,5-bis(3-alkylthiophen-2-yl)thienol	6
	[3,2b]t	hiophene)s (pBTTT)	
	2.2.3	Poly(methyl methacrylate) (PMMA)	6
2.3	Small Mo	lecules	7
	2.3.1	Vacuum Deposited Small Molecule	7
		(i) Bulkminsterfullrene (C60)	8
		(ii) Tetracene (C <sub>18</sub> H <sub>12</sub> )	8
	2.3.2	Solution Deposited Small Molecule	8
2.4	Deposition	on Techniques	10
	2.4.1	Vacuum Deposition	10
	2.4.2	Organic Vapor Phase Deposition (OVPD)	11
	2.4.3	Drop Casting	11
	2.4.4	Spin Coating	12
	2.4.5	Dip Coating	12
	2.4.6	Slide Coating	13
CH	APTER 3:	METHODOLOGY	
3.1	Chapter	Overview	16
3.2		n Methodology Flow	16
3.3	·	on of TIPS-pentacene onto borosilicate glass	20
	3.3.1	Cleaning Process of Borosilicate Glass as Transparent	21
	Subst	rate.	
	3.3.2	TIPS-pentacene Solution Preparation	22
	3.3.3	Deposition Techniques for TIPS-pentacene	22
		(i) Drop Casting	22
		(ii) Dip Coating	23



		(iii)	Spin Coating	25
		(iv)	Slide Coating	25
	3.3.4	TIPS-p	entacene Enhancement	26
		(i)	Furnace Time for TIPS-pentacene	27
		(ii)	Weight Percentage (wt%) of TIPS-pentacene	27
3.4	TIPS-per	ntacene	based Organic Semiconductor Diode Structures	27
3.5	Characte	erization	and Analysis	28
	3.5.1	X-ray	Diffraction (XRD)	28
	3.5.2	Surfac	e Morphology and Topography	29
		(i)	Scanning Electron Microscope (SEM)	29
		(ii)	Atomic Force Microscope (AFM)	30
		(iii)	Surface Profilemeter	31
3.6	Electrica	l Chara	cterization	31
	3.6.1	Effect	s of Solvents	32
CHA	PTER 4	RESU	LT	
4.1	Chapter	Overvi	ew	34
4.2	Charact	erizatio	n and Analysis of TIPS-pentacene	34
	4.2.1	TIPS-	pentacene Morphology	34
			pentacene Molecular Orientation	35
4.3	Analysis	of Diff	erent Deposition Techniques for TIPS-pentacene	38
	4.3.1	Morph	nology Analysis for TIPS-pentacene deposited	38
	using	Drop C	asting, Dip Coating, Spin Coating and Slide	
	Coati	ng		
4.4			ace Time for TIPS-pentacene	41
4.5	Compar	rison of	Different Weight Percentage for TIPS-pentacene	43



4.6 Electrical Characterization and Analysis for TIPS-pentacene	44
based Organic Semiconductor Diode	
4.6.1 Conduction Mechanism for ITO/TIPS-	44
pentacene/Aluminum Organic Diode Device	
CHAPTER 5: CONCLUSION	
5.1 Conclusion	53
5.2 Further Recommendation	54
REFERENCES	
APPENDICES	



### LIST OF TABLES

		Page
Table 3.1:	Compilation experiment for different deposition	21
, 45.0	techniques with allocated alignment	
Table 3.2:	Compiled Dip Coating deposition techniques alignment	23
	experiment	
Table 4.1:	Full width half maximum (FWHM) for Pentacene and	38
	TIPS-pentacene peaks.	
Table 4.2:	Different deposition techniques of (a) Drop Casting, (b)	39
	Spin Coating, (c) Dip Coating and (d) Slide Coating	
	characterized from Surface Profiler for approximate	
	thickness, surface roughness (RMS) and images.	
Table 4.3:	A (0 0 1) angle degree full width half maximum (FWHM)	41
	for drop casting and slide coating techniques.	
Table 4.4:	Full width half maximum (FWHM) for TIPS-pentacene	44
	with different weight percentage.	
Table 4.5:	Results of electrical characterization for ITO/TIPS/AL	48
	organic diode device	
Table 4.6:	FWHM calculated for (0 0 1) peak for toluene and	49
	chloroform solvent used to dilute TIPS-pentacene	
Table 4.7:	Comparison table for electrical analysis of TIPS-pentacene	51
	diluted in toluene and chloroform.	



### LIST OF FIGURES

		Page
Figure 2.1:	A poly(3-alkylthiophenes) chemical structure	5
Figure 2.2:	A poly(2,5-bis(3-alkylthiophen-2-yl)thieno(3,2-	6
rigure zizi	b)thiophene (pBTTT) chemical structures	
Figure 2.3:	A poly(methyl methacrylate) (PMMA) chemical structures	7
	Chemical structures of Tetracene C <sub>18</sub> H <sub>12</sub>	8
Figure 2.4:	Chemical structures of TIPS-pentacene (Ingram,	9
Figure 2.5:	2013)	
Figure 2.6:	Schematic drawing of vacuum thermal evaporation (Kovacik, t.th.)	10
Figure 2.7:	Schematic diagram of OVPD (Ling & Bao, 2004b)	11
Figure 2.7:	Schematic illustration for experimental and colloidal	14
Figure 2.8:	crystallization formation (Gil et al., 2010)	
Figure 3.1:	Overview flow chart procedure to fabricate TIPS-	18
rigule 3.1.	pentacene based organic diode	
Figure 3.2:	Flow chart of experimental procedure in fabrication	19
rigule 3.2.	and characterization of TIPS-pentacene based	
	diode	
Figure 3.3:	Drawings of fundamental step of Drop Casting	23
rigure 3.3.	deposition techniques	
Figure 3.4:	Drawings of fundamental step for Dip Coating	24
, igure or	deposition techniques	
Figure 3.5:	Drawings of fundamental Spin Coating deposition	25
riguio ete	techniques	
Figure 3.6:	Drawings of fundamental Slide Coating deposition	26
,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	techniques	
Figure 3.7:	Structures of TIPS-pentacene based organic	28
	semiconductor diode on transparent substrate	
Figure 4.1:	AFM images of drop casted TIPS-pentacene thin	35
· . <del>g.</del>	film onto transparent substrate with scanning size	
	of $25.0 \times 25.0$ nm <sup>2</sup> in (a) 2-dimensional (2D) and (b)	



	3-dimensional (3D) image. (c) SEM and Surface	
	Profilemeter analysis of TIPS-pentacene thickness	
	and surface roughness	
Figure 4.2:	Intensity versus degree graph comparison between	36
rigule 4.2.	Mohammad K.,2012 study of Pentacene deposited	
	via vacuum evaporation techniques (blue) and	
	TIPS-pentacene deposited via drop casting (red)	
Figure 4.3:	Top view (0 0 1) molecular orientation of TIPS-	37
rigule 4.5.	pentacene on transparent substrate based on two-	
	dimensional XRD data.	
Figure 4.4:	XRD result of drop casting, dip coating, spin coating	40
rigure 4.4.	and slide coated TIPS-pentacene small molecule	
	organic semiconductor.	
Figure 4.5:	XRD result of different duration time of furnacing	42
rigure 1.3.	TIPS-pentacene	
Figure 4.6:	FWHM versus furnace duration of TIPS-pentacene	42
rigare no.	deposited using slide coating method	
Figure 4.7:	XRD graph comparison for 0.05wt%, 0.1wt% and	43
rigure 1.71	0.2wt% of TIPS-pentacene organic solution	
Figure 4.8:	Current density, J versus voltage graph for	45
riguic net	ITO/TIPS-pentacene/Al organic diode with the	
	value of J <sub>max</sub> obtained 1.33x10 <sup>-7</sup> A/cm <sup>2</sup>	
Figure 4.9:	A current versus voltage graph for ITO/TIPS-	46
rigure	pentacene/Al organic diode device to achieve its	
	turn on value, V₁, of 2.22V	
Figure 4.10:	Saturation current, $I_0$ values of 19.32A by log I	46
i iguio iliza	versus V graph	
Figure 4.11:	dV versus dlnI graph plotted to obtain barrier	47
riguio il	height, $\phi_b$ from the y-axis intercept; and ideality	
	factor, n, by obtaining gradient of the graph	
Figure 4.12:	Resistance versus voltage graph to obtain sheet	47
	resistance, $R_{\mbox{\scriptsize s}}$ from the lowest value of the data,	
	which is $8.75 \times 10^6 \Omega$	



Figure 4.13:	XRD graph comparison between TIPS-pentacene	48
rigure ii.zo.	diluted solvent between chloroform and toluene	
Figure 4.14:	I-V graph comparison between chloroform and	49
rigare iiz ii	toluene as TIPS-pentacene solvent	
Figure 4.15:	Semi-log current versus voltage graph to obtain	50
rigare ii.zoi	saturation current, $I_0$ based on y-intercept values.	
Figure 4.16:	Log-I versus voltage graph plotted to find its	50
rigure neo	ideality factors n barrier heights for TIPS-pentacene	
	diluted in chloroform and toluene	
Figure 4.17:	Forward biased resistance versus voltage graph for	51
riguic nazz	TIPS-pentacene diluted in toluene and chloroform	



### LIST OF ABBREVIATIONS

TIPS-pentacene 3,16-bis(triisopropylsilylethynyl) pentacne

IV current voltage

OLED organic light-emitting diodes
OFET organic field effect transistors

OSC organic Schottky diode

RPM rotation per minute

weight percentage

wt% weight percentage
P3HT Poly(3-hexylthiophene)

pBTTT Poly(2,5-bis(3-alkylthiophen-2-yl)thienol (3,2-b)thiophene)s

C<sub>60</sub> Bulkminsterfullrene

C<sub>18</sub>H<sub>12</sub> Tetracene C<sub>22</sub>H<sub>14</sub> Pentacene

TIPS- 2,9-bis(triisopropysilylethynyl) triphenodioxazine

Ttriphenodioxazine

PMMA Poly(methylmethacrylate)

OVPD Organic vapor phase deposition

FWHM Full width half maximum

XRD X-ray diffraction

SEM Scanning Electron Microscope

AFM Atomic Force Microscope

ITO Indium Tin Oxide
SE Secondary Electron

BSE Backscattered Electron

SMU Source Meter Unit

RMS Surface Roughness

2D 2-dimentional 3-dimentional

MOM Metal-organic-metal

HOMO Highest occupied molecular orbital



# LIST OF SYMBOLS

Degree
Celsius
Current density
Turn-on Voltage
Saturation Current
Barrier Heights
Sheet Resistance
Ideality factor
Full width half maximum
Wavelength
Biased voltage
Electronic charge
Boltzmann's constant
Absolute temperature
Effective area of diode
Richardson's constant



# LIST OF APPENDICES

		Page
ADDENIDIY A	TIPS-pentacene Material Safety Data Sheet	59
ADDENIDIY R	ITO Coated Glass Substrate for Organic Dielectric	63
	Lists of Publication	64



### **CHAPTER 1**

### INTRODUCTION

### 1.1 Background

The application of organic semiconductor has seized different types of devices such as organic light-emitting diodes (OLED), organic field effect transistors (OFET) and organic Schottky diodes (OSD). Conventional inorganic material-based devices are stable but not as variety in terms of presentation. Today's gadgets require it to be fancy but efficient to keep up with the latest design. Therefore, organic materials are a good option as it can be fabricated onto solid nor flexible surfaces that will result in a more futuristic presentation towards the electronic devices.

6, 13 bis-triisopropylsilylethynyl (pentacene) (TIPS-Pentacene) commonly used as an organic material for semiconductor layer as it values high measured mobility values 0.401 cm²/Vs for drop casted deposition technique and thermally annealed (Bae *et al.*, 2010). This is due to the existing side chains in TIPS-pentacene that helps to increase solubility in organic solvents (Bae *et al.*, 2010; Chen *et al.*, 2008). The presence of bulky groups also assisted the face-to-edge herringbone packing pattern to form stacking between all planes (Chen *et al.* 2008).

## 1.2 Problem Statement

This research is on slide coating as deposition methods for small molecule organic semiconductor, understanding its optimum condition to achieve highly oriented molecular properties. Comparable to other deposition method such as drop



casting, the films formed are adequate for it to be fabricated into a device; the ability to control directions of solution drying area will be more helpful as it influences the electrical performance of one device. Therefore, slide coating techniques can control formation of thin film microsphere and produces high quality colloidal crystals.

# 1.3 Research Objective

The aim of this research is to fabricate a TIPS-pentacene based organic semiconductor diode. The objectives in accomplishing this project is highlighted as follow:

- (i) To characterize and compare various techniques for TIPS-pentacene deposition thin film.
- (ii) To analyse the physical properties and electrical characteristics of TIPSpentacene thin film deposited using slide coating at different annealing time and solution concentration.

### 1.4 Research Scope

This research is to achieve the optimum parameter of depositing TIPS-pentacene with partial mechanical appliance for deposition source used. Partial here revenues as some of the deposition used such as drop casting, dip coating and slide coating were using non-mechanical method, whilst spin coating uses a mechanical deposition with selected rotation per minute (RPM). For dip coating deposition technique, the experiment was conducted near 90° and 180° angle for vertical and horizontal alignment, respectively. This is due to the limitation of apparatus to conduct it in a precise 90° and 180° angle, hence the non-mechanical method. Parameters involved in order to find optimum TIPS-pentacene deposition were different deposition techniques such as drop casting, dip coating, spin coating and slide coating. Optimum alignment for dip coating, spin coating and slide coating were evaluated. Furnace time and different weight percentage (wt%) for TIPS-pentacene deposition were also being measured.

For electrical characterization, different length for two different contacts, different choices of solvent and contact placement to measure current-voltage (I-V) performance based on TIPS-pentacene as semiconductor layer are also included in



this research. The experiment conducted for TIPS-pentacene deposited was performed in a normal room temperature without any presence of clean room and vacuumed air chamber.

### 1.5 Thesis Outline

This research thesis consists of 5 chapters. Chapter 1 explains more on the introductory to organic semiconductor fields, problem statements, research objectives and scope were presented in this chapter.

Chapter 2 designates more on the core theories intricate to fabricate TIPS-pentacene based organic semiconductor diode. Fundamental concept such as identifying the morphologies and topographies of an ideal thin film is explained in this chapter. Basic theories on characterization using XRD, SEM, AFM, Surface profilometer and I-V measurement tools are included.

Detailed experimental steps on how to achieve ideal deposited thin films and organic semiconductor diode are explained in Chapter 3. Followed by the obtained results are presented and analysed in Chapter 4. Conclusion for this study and further suggestion or enhancement for this study is presented in the final chapter.



### **CHAPTER 2**

## LITERATURE REVIEW

# 2.1 Organic Semiconductors

For the past few decades, organic based electronics has gained attentions due to its capability of straight forward deposition techniques and low upkeeps, especially towards devices that requires large area coverage (Lee & Park, 2014; Choi *et al.*, 2012; Kim *et al.*, 2008). Organic based semiconductor has the capacity to compensate existing inorganic based semiconductor device, as inorganic fabrication techniques requires for it to be execute on high temperature and vacuum mode environment (Baklar, 2010; Lee & Park, 2014; Parry, 2013; Kim *et al.*, 2008; Saeed *et al.*, t.th.; Chung *et al.*, 2010). Generally, organic semiconductors are divided into two groups: micromolecular, which consists of sub-unit of small molecules semiconductors and oligomers; and other group, is macromolecular or also known as polymers. These groups are categorized according to the crystal stacking an its molecular orientation (Saeed *et al.*, t.th.).The significant contrast between both groups are the amount of molecular weight, where polymer has higher numbers of molecules (Baklar, 2010).

Both micro- and macromolecular organic materials can be shaped into solution form, which explains the straightforward deposition techniques and free from complex apparatus (Zhao, H. *et al*, 2015). Examples of deposition techniques available are drop casting, dip coating, spin coating and slide coating (Baklar, 2010; Lee & Park, 2014; Parry, 2013; Kim *et al.*, 2008; Akkerman *et al.*, 2012; Schols, 2011). One of the biggest concerns using organic material is the durability when it is bared to air and light, but



alteration in the molecular structure of the organic material can overcome this problem (Baklar, 2010). The possibilities for organic based device are unlimited and were predicted to potentially replace the existing inorganic electronic production (Baklar, 2010; Parry, 2013).

### 2.2 Polymers

As explained in previous paragraph, the differences between a polymer and small- molecule organic materials are the structures, as the words poly- itself clearly disclose that polymer has longer structure (Baklar, 2010). Therefore, polymer are more malleable, have higher heat resistance and suitable for flexible based electronic devices (Baklar, 2010). Polymer's solubility ability were improved by adding side-chains to the structures, as most used conjugated structures for polymer semiconductors are poly(3-hexylthiophene) (P3HT) and latest technology findings like liquid-crystalline polymer known as poly(2,5-bis(3alkilthiophen-2-yl)thieno[3,2-b]thiophene) (pBTTT) as derivatives shown up to 1.0cm<sup>2</sup>V<sup>-1</sup>s<sup>-1</sup> mobility performance (Huang, 2009).

# 2.2.1 Poly(3-alylthiohene) (P3HT)

A regio-isomers can be formed depends on how the chains stacked; either head-to-tail, tail-to-tail or head-to-tail arrangements. Therefore, P3HT's polymer structures on how it is arranged based on region-isomer's variety will affects the performance of the electronic devices (Baklar, 2010). A P3HT is known to have good adhesiveness and mechanical properties that often used as reference to other compounds (Baklar, 2010). Despite the advantages, P3HT also experiences expiry when placed in open air (Baklar, 2010).

Figure 2.1: A poly(3-alkylthiophenes) chemical structure.



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